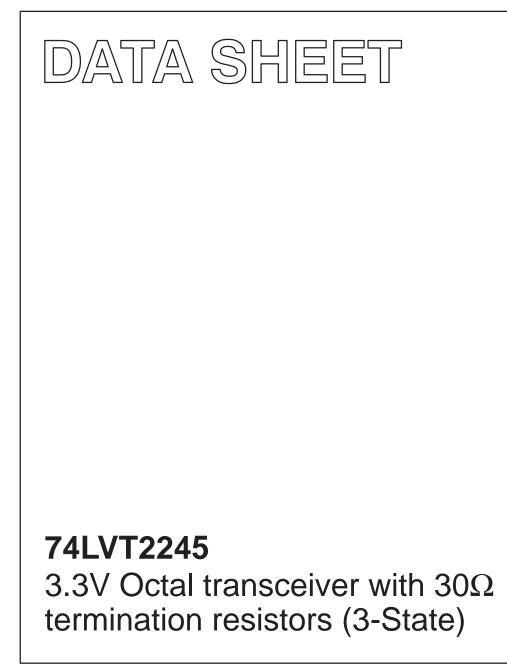
INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Mar 11 IC23 Data Handbook

1998 Feb 19





74LVT2245

FEATURES

- 30Ω output termination resistors
- Octal bidirectional bus interface
- 3-State buffers
- Output capability: +12mA/-12mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

QUICK REFERENCE DATA

DESCRIPTION

The LVT2245 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (\overline{OE}) input for easy cascading and a Direction (DIR) input for direction control.

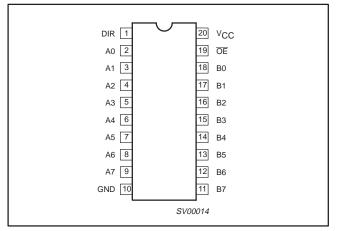
The 74LVT2245 is designed with 30Ω series resistance in both the High and Low states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus transceivers/transmitters.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	$C_L = 50 pF;$ $V_{CC} = 3.3 V$	3.2 3.1	ns
C _{IN}	Input capacitance DIR, OE	V _I = 0V or 3.0V	4	pF
C _{I/O}	I/O pin capacitance	Outputs disabled; $V_{I/O} = 0V \text{ or } 3.0V$	10	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	0.13	mA

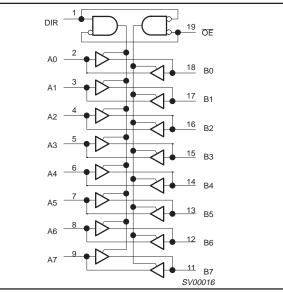
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SO	–40°C to +85°C	74LVT2245 D	74LVT2245 D	SOT163-1
20-Pin Plastic SSOP	–40°C to +85°C	74LVT2245 DB	74LVT2245 DB	SOT339-1
20-Pin Plastic TSSOP	−40°C to +85°C	74LVT2245 PW	7LVT2245PW DH	SOT360-1

PIN CONFIGURATION

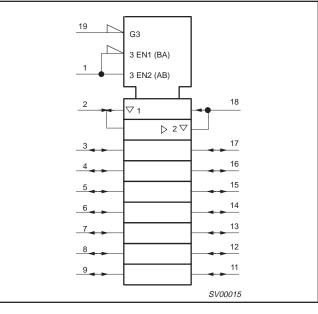


LOGIC SYMBOL



74LVT2245

LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	ŌĒ	Output enable input (active–Low)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

ABSOLUTE MAXIMUM RATINGS^{1,2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
		Output in Low state	128	
IOUT	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction

temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

FUNCTION TABLE

INP	UTS	INPUTS/OUTPUTS		
<u>OE</u> n	DIR	An	Bn	
L	L	An= Bn	Inputs	
L	Н	Inputs	Bn =An	
Н	Х	Z	Z	

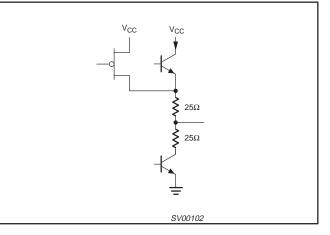
H = High voltage level

L = Low voltage level

X = Don't care

Z = High impedance "Off" state

SCHEMATIC OF EACH OUTPUT



74LVT2245

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	LIMITS		
STMBOL	TANAMETER	MIN	MAX	UNIT	
V _{CC}	DC supply voltage	2.7	3.6	V	
VI	Input voltage	0	5.5	V	
V _{IH}	High-level input voltage	2.0		V	
V _{IL}	Input voltage		0.8	V	
I _{OH}	High-level output current		-12	mA	
I _{OL}	Low-level output current		12	mA	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V	
T _{amb}	Operating free-air temperature range	-40	+85	°C	

DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	= −40°C to	+85°C	UNIT
				MIN	TYP ¹	MAX	
VIK	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-0.9	-1.2	V
V _{OH}	High-level output voltage	$V_{CC} = 3.0V; I_{OH} = -12mA$		2.0	2.2		V
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 12mA				0.8	V
		$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{\text{I}} = 5.5 \text{V}$	Control pins		1	10	
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$	Control pins		±0.1	±1	
I _I	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V$			1	20	μA
		$V_{CC} = 3.6V; V_I = V_{CC}$	I/O Data pins ⁴		0.1	1	
		$V_{CC} = 3.6V; V_{I} = 0$	1		-1	-5	
I _{OFF}	Output off current	$V_{CC} = 0V$; V_{I} or $V_{O} = 0$ to 4.5V			1	±100	μA
		$V_{CC} = 3V; V_I = 0.8V$		75	150		
I _{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-150		μA
		$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			
I_{EX}	Current into an ouptut in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 3.0V$			60	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GND$ or V_{CC} ; $OE/OE = Don't$ care			15	±100	μA
I _{ССН}		V_{CC} = 3.6V; Outputs High, V_{I} = GND or	V_{CC} , $I_{O} = 0$		0.13	0.19	
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_{I} = GND or	V _{CC} , I _{O =} 0		3	12	mA
I _{CCZ}	1	V_{CC} = 3.6V; Outputs Disabled; V_I = GNI		0.13	0.19		
ΔI_{CC}	Additional supply current per input pin ³	V_{CC} = 3V to 3.6V; One input at V _{CC} -0.6 Other inputs at V _{CC} or GND	V,		0.1	0.2	mA

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND 3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2V$ to $V_{CC} = 3.3V \pm 0.3V$ a transition time of 100µsec is permitted. This parameter is valid for $T_{amb} = +25^{\circ}C$ only.

4. Unused pins at V_{CC} or GND.

5. I_{CCZ} is measured with outputs pulled up to V_{CC} or down to GND

6. This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

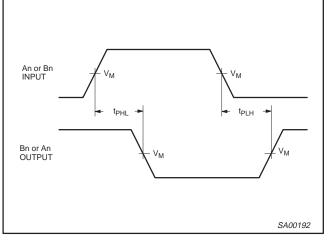
			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	Vcd	; = 3.3V +0	.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP	MAX	МАХ	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	1	1.0 1.0	3.2 3.1	4.6 4.5	5.3 4.9	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.1 1.5	4.5 4.3	7.0 6.5	9.1 7.6	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	2.2 2.0	3.7 3.6	5.2 5.0	5.6 5.0	ns

NOTE:

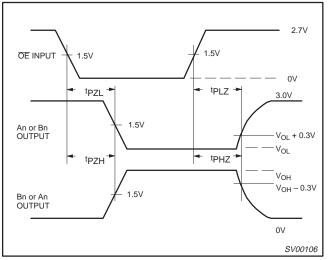
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25^{\circ}C.

AC WAVEFORMS

 V_{M} = 1.5V, V_{IN} = GND to 2.7V



Waveform 1. Input (An or Bn) to Output (Bn or An) Propagation Delays

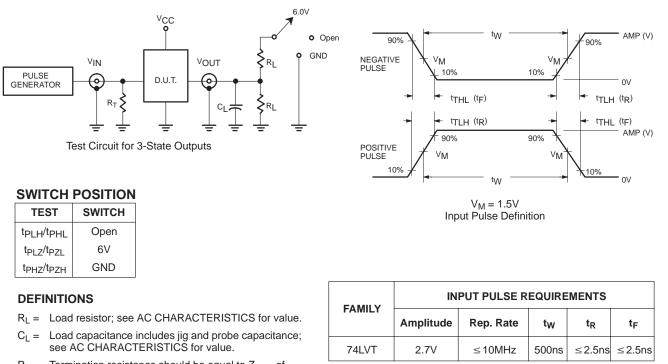


Waveform 2. 3-State Output Enable and Disable Times

Product specification

74LVT2245

TEST CIRCUIT AND WAVEFORMS

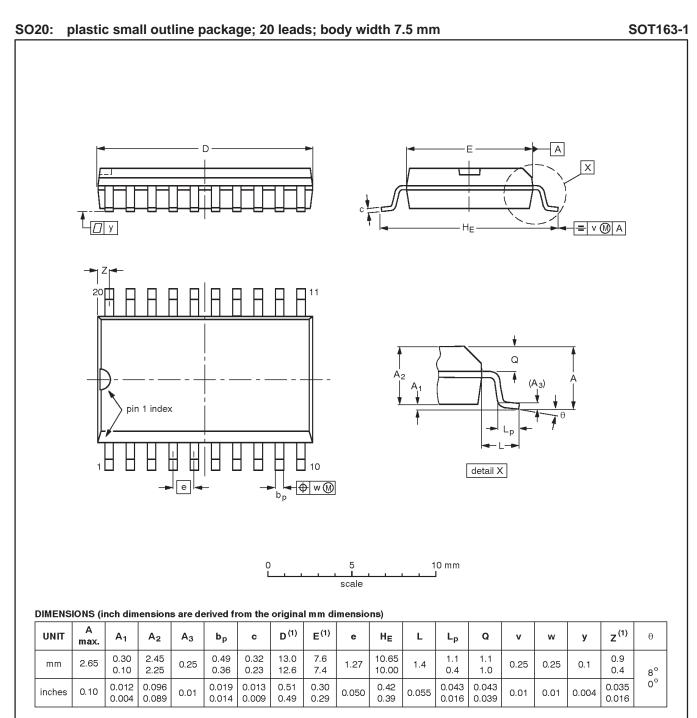


 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

SV00092

Product specification

74LVT2245



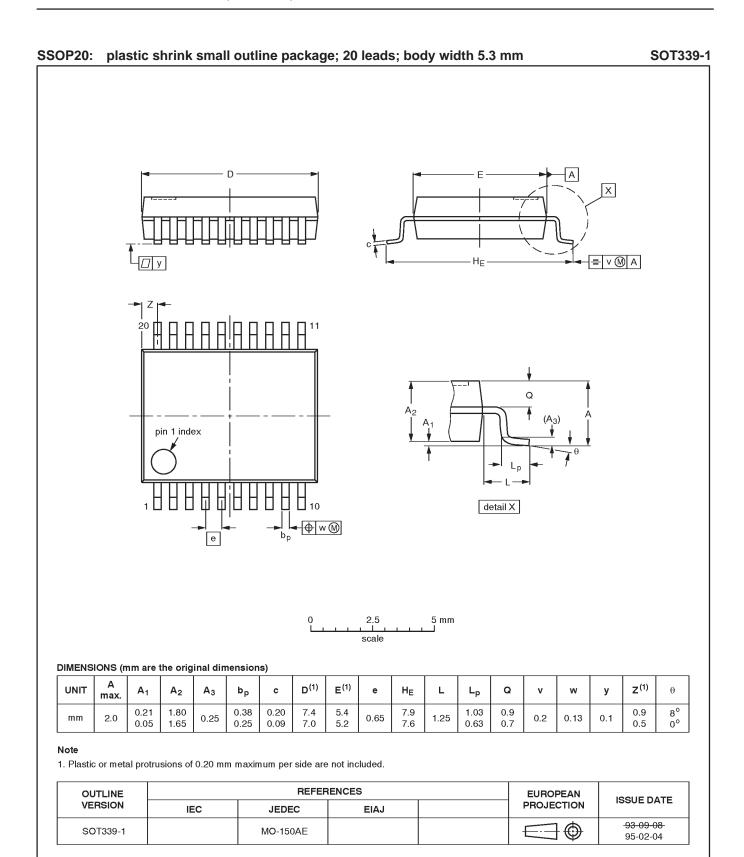
Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

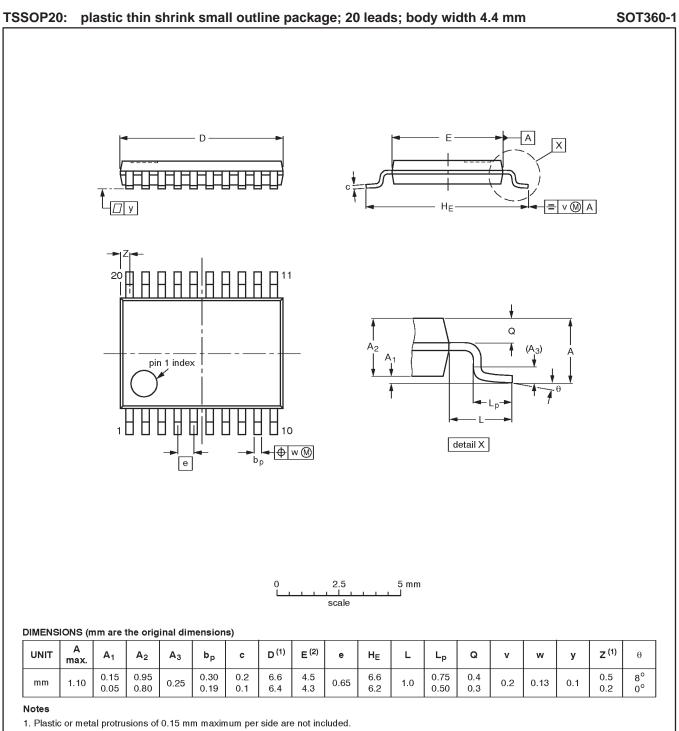
OUTLINE		REFERENCES				EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1350E DATE		
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24		

Product specification

74LVT2245



74LVT2245



2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT360-1		MO-153AC				-93-06-16 95-02-04	

74LVT2245

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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